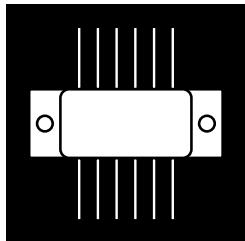


DUAL HIGH POWER, HIGH CURRENT OPERATIONAL AMPLIFIER MODULE



12 Pin, Dual Uncommitted Power Operational Amplifiers And Power Sense Resistors

FEATURES

- Dual Op Amps - Uncommitted
- Dual Sense Resistors - Uncommitted
- Output Current To 10A Peak
- Power Supply To $\pm 40V$
- FET Input
- Hermetic Package - Isolated Devices
- Available Screened To MIL-STD-883

DESCRIPTION

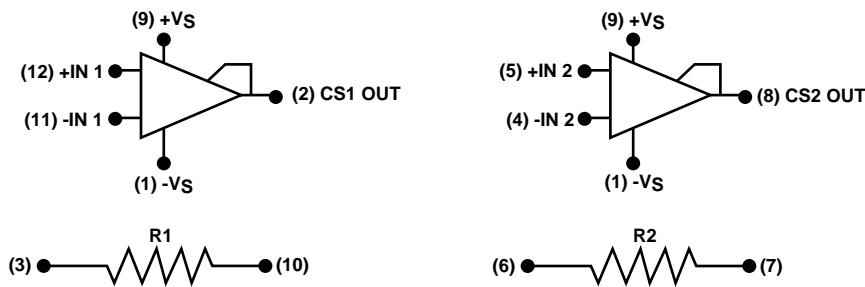
The OMA8201SF is a high performance hybrid integrated circuit which contains two (2) uncommitted power amplifiers and two (2) high power sense resistors. The device is ideally suited for high density and high reliability systems. The sense resistor can be customized for specific applications, however $R_{min} = 20\text{ m}\Omega$.

ABSOLUTE MAXIMUM RATINGS (Per Device) @ 25°C

Supply Voltage $+V_S$ to $-V_S$	80V
Output Current, Continuous.....	5A
Power Dissipation, Internal	125W
Resistor Dissipation, Maximum.....	5W
Operating Temperature Range	- 55°C to + 125°C
Storage Temperature Range	- 55°C to + 150°C
Maximum Junction Temperature	150°C
Lead Temperature (10 Sec. Soldering).....	300°C

SCHEMATIC

3.4



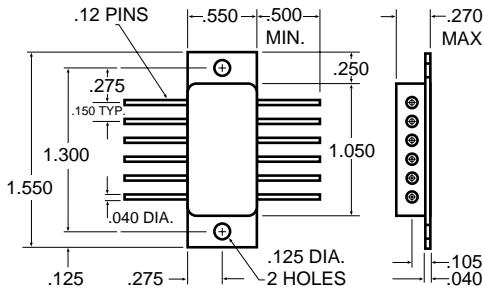
OMA8201SF

ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$; $V_s = \pm 34 \text{ V}_{\text{DC}}$ unless otherwise noted.)

Parameter	Conditions	Min.	Typ.	Max.	Units
Input Offset Voltage					
V_{os}			.01	.2	mV
vs Temperature	-25°C to +125°C		.15	.30	µV/°C
vs Temperature	-55°C to -25°C		.20	.40	µV/°C
vs Supply Voltage	$V_s = \pm 10\text{V}$ to $\pm V_{\text{MAX}}$.25	.10	µV/V
vs Power			.20	.60	µV/W
Input Bias Current					
I_b	Specified Temperature Range		20	50	nA
Input Offset Current					
I_{os}	Specified Temperature Range		.5	.20	nA
Input Characteristics					
Common-Mode Voltage Range	-55°C to +85°C		$\pm(\partial V_{os}/6)$	$\pm(\partial V_{os}/3)$	V
	+85°C to +125°C		$\pm(\partial V_{os}/6.5)$	$\pm(\partial V_{os}/3.2)$	V
Common-Mode Rejection	$V_{CM} = \pm(\partial V_{os}/6\text{V})$		95	113	dB
	$V_{CM} = \pm 22\text{V}$			5	dB
Input Capacitance*				1	pF
Input Capacitance, DC*					T
Gain Characteristics					
Open Loop Gain at 10Hz		90	97		dB
Gain Bandwidth Product*			1.6		MHz
Output					
Voltage Swing	$I_o = 5\text{A}$, Continuous		$\pm(\partial V_{os}/5.5)$	$\pm(\partial V_{os}/4.5)$	V
	$I_c = 25\text{A}$, $T_c = 125^\circ\text{C}$		$\pm(\partial V_{os}/4)$	$\pm(\partial V_{os}/3.6)$	V
	$T_c = -55^\circ\text{C}$		$\pm(\partial V_{os}/6)$	$\pm(\partial V_{os}/5.5)$	V
Current Peak		9	10		A
AC Performance					
Slew Rate		6	10		V/µS
Power Bandwidth*	$R_L = 8$, $V_o = 20\text{V}_{\text{rms}}$		55		kHz
Setting Time to 0.1%*	2V Step		2		µS
Capacitive Load*	Specified Temperature Range, $G = 1$	3.3			nF
Phase Margin*	Specified Temperature Range, $G > 10$		40	SOA	Degrees
Phase Margin*	Specified Temperature Range, $R_L = 8$				
Power Supply					
Power Supply Voltage, $\pm V_s$		± 10	± 35	± 40	V
Current Quiescent	Specified Temperature Range		50	70	mA
Thermal Resistance					
q_{JC} (Junction-to-Case)	AC Output, $f < 60\text{Hz}$		1.25	1.5	°C/W
q_{JA} (Junction-to-Ambient)	DC Output		1.4	1.9	°C/W
	No Heat Sink		30		°C/W

Notes: *Guaranteed - not tested 100%.

MECHANICAL OUTLINE



PIN CONNECTION

